

MMSTA63/MMSTA64 PNP SURFACE MOUNT DARLINGTON TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Complementary NPN Types Available (MMSTA13/MMSTA14)
- Ultra-Small Surface Mount Package
- Ideal for Medium Power Amplification and Switching
- **High Current Gain**
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-323 •
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMSTA63 Marking K2E, K3E, See Page 3
- MMSTA64 Marking K3E, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)

	SOT-323	;
Dim	Min	Max
Α	0.25	0.40
В	1.15	1.35
С	2.00	2.20
D	0.65 N	ominal
Е	0.30	0.40
G	1.20	1.40
Н	1.80	2.20
J	0.0	0.10
Κ	0.90	1.00
L	0.25	0.40
М	0.10	0.18
α	0°	8°
All Dir	nensions	in mm

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	-30	V	
Collector-Emitter Voltage	V _{CEO}	-30	V	
Emitter-Base Voltage	V _{EBO}	-10	V	
Collector Current - Continuous	lc	-500	mA	
Power Dissipation (Note 1)	Pd	200	mW	
Thermal Resistance, Junction to Ambient (Note 1)	R ₀ JA	625	C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C	

→IAŀ

-B С

Notes:

Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, 1. which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php 3.

Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date 4. Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

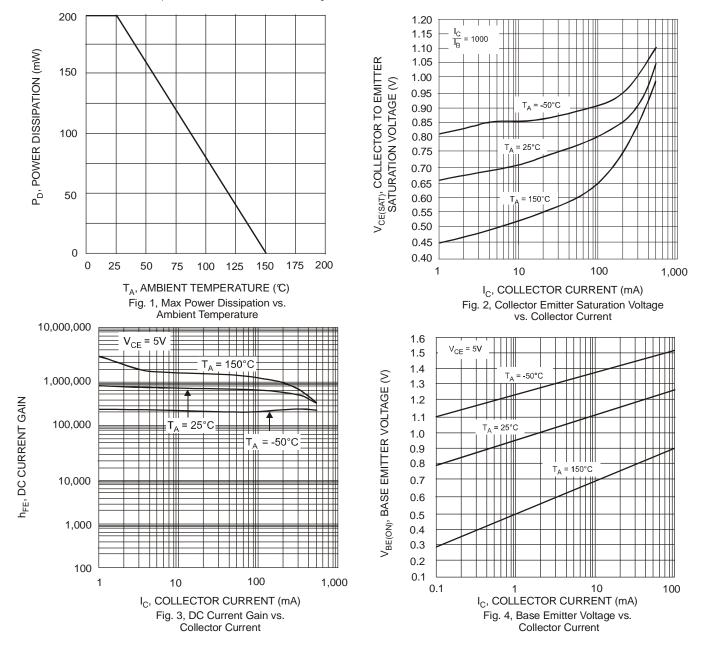


Electrical Characteristics @T_A = 25°C unless otherwise specified

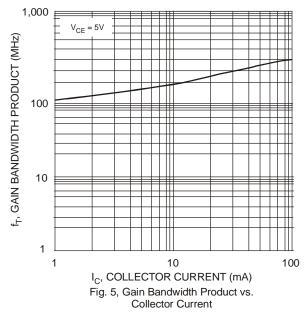
Characteristic	Symbol	Min	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)							
Collector-Emitter Breakdown Voltage		V _{(BR)CEO}	-30		V	$I_{C} = -100 \mu A V_{BE} = 0 V$	
Collector Cutoff Current		I _{CBO}	_	-100	nA	$V_{CB} = -30V, I_E = 0$	
Emitter Cutoff Current		I _{EBO}		-100	nA	$V_{EB} = -10V, I_{C} = 0$	
ON CHARACTERISTICS (Note 5)							
DC Current Gain	MMSTA63 MMSTA64 MMSTA63 MMSTA64	h _{FE}	5,000 10,000 10,000 20,000	_	_	$\label{eq:lc} \begin{array}{ll} I_C = & -10 \text{mA}, \ V_{CE} = -5.0 \text{V} \\ I_C = & -10 \text{mA}, \ V_{CE} = -5.0 \text{V} \\ I_C = & -100 \text{mA}, \ V_{CE} = -5.0 \text{V} \\ I_C = & -100 \text{mA}, \ V_{CE} = -5.0 \text{V} \end{array}$	
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	_	-1.5	V	$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -100 {\rm \mu A}$	
Base- Emitter Saturation Voltage		V _{BE(SAT)}	_	-2.0	V	$I_{C} = -100 \text{mA}, V_{CE} = -5.0 \text{V}$	
SMALL SIGNAL CHARACTERISTICS							
Current Gain-Bandwidth Product		f⊤	125	—	MHz	$V_{CE} = -5.0V, I_C = -10mA, f = 100MHz$	



5. Short duration pulse test used to minimize self-heating effect.





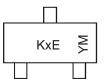


Ordering Information (Note 4 & 6)

Device	Packaging	Shipping
MMSTA63-7-F	SOT-323	3000/Tape & Reel
MMSTA64-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



 $\begin{array}{l} \mathsf{KxE} = \mathsf{Product Type Marking Code, e.g. K2E} = \mathsf{MMSTA63}\\ \mathsf{YM} = \mathsf{Date Code Marking}\\ \mathsf{Y} = \mathsf{Year ex: N} = 2002\\ \mathsf{M} = \mathsf{Month ex: 9} = \mathsf{September} \end{array}$

Date Code Key															
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	к	L	М	Ν	Р	R	s	Т	U	V	W	Х	Y	Z
Month	Jan	Fe	b I	Mar	Apr	Мау	Ju	n	Jul	Aug	Sep	Oc	t I	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		Ν	D

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